Seat No.: _____ Enrolment No.

GUJARAT TECHNOLOGICAL UNIVERSITY

BE- SEMESTER–V (NEW) EXAMINATION – WINTER 2020

Subject Code:3151105 **Date:03/02/2021**

Subject Name:VLSI Design

Time:10:30 AM TO 12:30 PM **Total Marks: 56**

Instructions:

1. **Attempt any FOUR questions out of EIGHT questions.**
2. **Make suitable assumptions wherever necessary.**
3. **Figures to the right indicate full marks.**

			MARKS
Q.1	**(a)**	Draw CMOS inverter circuit and cross section view of nMOSFET.	**03**
	(b)	Draw voltage transfer characteristics of inverter and define V_{IL}, V_{IH}, V_{OL}, V_{OH}, NM_L and NM_H.	**04**
	(c)	Derive threshold voltage equation and explain what is substrate bias effect.	**07**
Q.2	**(a)**	Realize following Boolean logic equation using CMOS inverter. Z= (AB+C(D+E))'	**03**
	(b)	Compare Static and Dynamic logic circuit.	**04**
	(c)	Derive drain current using gradual channel approximation.	**07**
Q.3	**(a)**	Draw VTC of CMOS inverter and find operating region of NMOS and PMOS at different input voltage ranges from 0 to Vdd.	**03**
	(b)	Derive Critical voltages V_{IL} and V_{IH} of CMOS inverter	**04**
	(c)	Consider a CMOS inverter with the following parameters: VTon = 0.6 V, VTop = - 0.7 V ,Kn' = 50 uA/V^2, Kp' = 16 uA/V^2, (W/L)n = 4, (W/L)p = 5 Calculate the noise margins of this circuit. The power supply voltage is VDD = 3.3 V.	**07**
Q.4	**(a)**	Draw resistive load inverter circuit and its VTC curve.	**03**
	(b)	Derive critical voltages V_{OH}, V_{OL}, V_{IL} and V_{IH} of resistive load inverter.	**04**
	(c)	Design resistive load inverter with following parameters: VTon = 0.8 V, Kn' = 20 uA/V^2, (W/L)n = 2, R_L= 200 kohm and Vdd=5V. Calculate the noise margins of this circuit.	**07**
Q.5	**(a)**	Draw transistor level circuit diagram of NOR based SR latch using CMOS.	**03**
	(b)	Derive switching power dissipation equation of CMOS inverter with idea step input.	**04**
	(c)	Justify importance of transmission gate. Realize following functions using TG. i) F=AB+A'C'+AB'C and ii) F=AB' + A'B	**07**
Q.6	**(a)**	What is need of domino CMOS logic circuit and draw it's circuit diagram.	**03**

	(b)	Explain Ring oscillator.	**04**
	(c)	Draw i/p and o/p waveform during high to low transition of o/p for CMOS inverter and derive expression for τ_{PHL}. using differential equation method.	**07**
Q.7	**(a)**	Draw CMOS implementation of D latch with two inverters and two CMOS TG gates.	**03**
	(b)	Compare CPLD and FPGA.	**04**
	(c)	Draw and Explain different clock generator and distributor circuits	**07**
Q.8	**(a)**	Compare FinFET and Planner MOSFET	**03**
	(b)	Compare constant voltage and constant filed scaling.	**04**
	(c)	What is need of Design of Testability (DFT) in VLSI IC design and explain Built in Self Test (BIST) techniques of DFT.	**07**

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